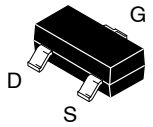
N-Channel RF Amplifier

MMBF5484, MMBF5485, MMBF5486

This device is designed primarily for electronic switching applications such as low On Resistance analog switching. Sourced from Process 50.



NOTE: Source & Drain are interchangeable

SOT-23
CASE 318

ABSOLUTE MAXIMUM RATINGS* (T_A = 25 °C unless otherwise noted)

Symbol	Rating	Value	Unit
V_{DG}	Drain-Gate Voltage	25	V
V_{GS}	Gate-Source Voltage	−25	V
I_{GF}	Forward Gate Current	10	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

* These rating are limiting values above which the serviceability of any semiconductor device may be impaired.

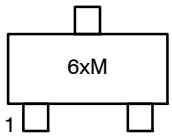
2. These rating are based on a maximum junction temperature of 150 °C.
3. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

Symbol	Characteristic	Max *MMBF5484-5486	Unit
P_D	Total Device Dissipation Derate above 25 °C	225 1.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	–	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	°C/W

* Device mounted on FR-4 PCB 1.6” x 1.6” x 0.06”.

MARKING DIAGRAM



6x = Device Code (x = B, M, H)
M = Date Code

ORDERING INFORMATION

Device	Package	Shipping†
MMBF5484	SOT-23 (Pb-Free)	3,000 Tape & Reel
MMBF5485		

DISCONTINUED (Note 1)

MMBF5486	SOT-23 (Pb-Free)	3,000 Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. **DISCONTINUED:** This device is not available. Please contact your **onsemi** representative for information. The most current information on this device may be available on www.onsemi.com.

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ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Typ	Max	Unit
OFF CHARACTERISTICS							
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	I_G = −1.0 μA, V_{DS} = 0		−25	–	–	V
I_{GSS}	Gate Reverse Current	V_{GS} = −20 V, V_{DS} = 0 V_{GS} = −20 V, V_{DS} = 0, T_A = 100 °C		– –	– –	−1.0 −0.2	nA μA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	V_{DS} = 15 V, I_D = 10 nA	*5484* *5485* *5486*	−0.3 −0.5 −2.0	– – –	−3.0 −4.0 −6.0	V V V
ON CHARACTERISTICS							
I_{DSS}	Zero-Gate Voltage Drain Current*	V_{DS} = 15 V, V_{GS} = 0	*5484* *5485* *5486*	1.0 4.0 8.0	– – –	5.0 10 20	mA mA mA
SMALL SIGNAL CHARACTERISTICS							
g_{fs}	Forward Transfer Conductance	V_{DS} = 15 V, V_{GS} = 0, f = 1.0 kHz	*5484* *5485* *5486*	3000 3500 4000	– – –	6000 7000 8000	μmhos μmhos μmhos
$Re(y_{is})$	Input Conductance	V_{DS} = 15 V, V_{GS} = 0, f = 100 MHz	*5484*	–	–	100	μmhos
		V_{DS} = 15 V, V_{GS} = 0, f = 400 kHz	*5485 / 5486*	–	–	1000	μmhos
g_{os}	Output Conductance	V_{DS} = 15 V, V_{GS} = 0, f = 1.0 kHz	*5484* *5485* *5486*	– – –	– – –	50 60 75	μmhos μmhos μmhos
$Re(y_{os})$	Output Conductance	V_{DS} = 15 V, V_{GS} = 0, f = 100 MHz	*5484*	–	–	75	μmhos
		V_{DS} = 15 V, V_{GS} = 0, f = 400 MHz	*5485 / 5486*	–	–	100	μmhos
$Re(y_{fs})$	Forward Transconductance	V_{DS} = 15 V, V_{GS} = 0, f = 100 MHz	*5484*	2500	–	–	μmhos
		V_{DS} = 15 V, V_{GS} = 0, f = 400 MHz	*5485* *5486*	3000 3500	– –	– –	μmhos μmhos
C_{iss}	Input Capacitance	V_{DS} = 15 V, V_{GS} = 0, f = 1.0 MHz		–	–	5.0	pF
C_{rss}	Reverse Transfer Capacitance	V_{DS} = 15 V, V_{GS} = 0, f = 1.0 MHz		–	–	1.0	pF
C_{oss}	Output Capacitance	V_{DS} = 15 V, V_{GS} = 0, f = 1.0 MHz		–	–	2.0	pF
NF	Noise Figure	V_{DS} = 15 V, R_G = 1.0 kΩ, f = 100 MHz	*5484*	–	–	3.0	dB
		V_{DS} = 15 V, R_G = 1.0 kΩ, f = 400 MHz	*5484*	–	4.0	–	dB
		V_{DS} = 15 V, R_G = 1.0 kΩ, f = 100 MHz	*5485 / 5486*	–	–	2.0	dB
		V_{DS} = 15 V, R_G = 1.0 kΩ, f = 400 MHz	*5485 / 5486*	–	–	4.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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TYPICAL CHARACTERISTICS

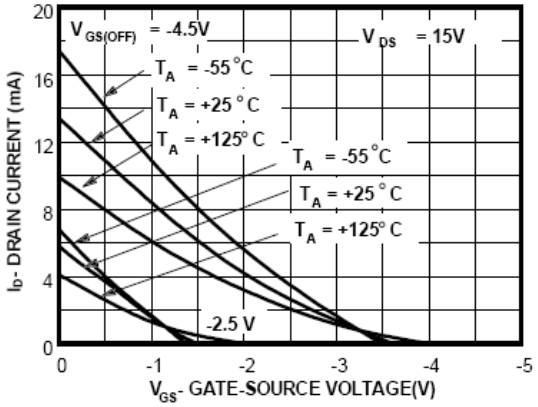


Figure 1. Transfer Characteristics

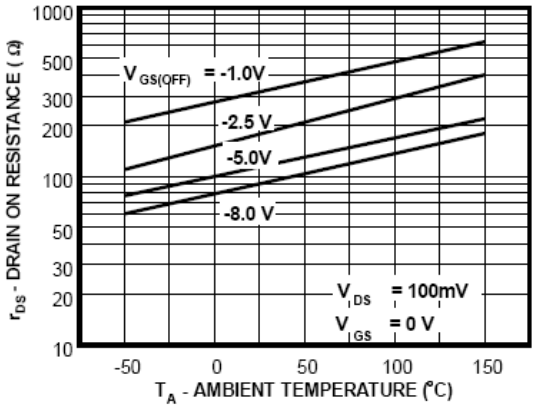


Figure 2. Channel Resistance vs. Temperature

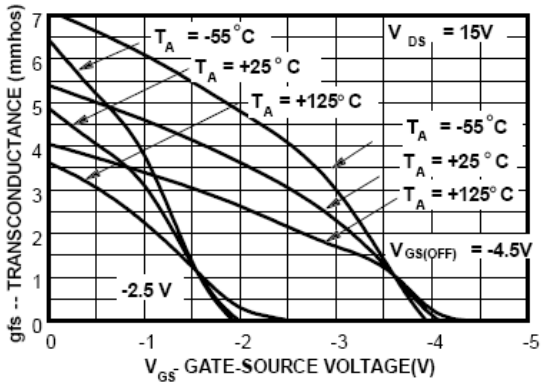


Figure 3. Transconductance Characteristics

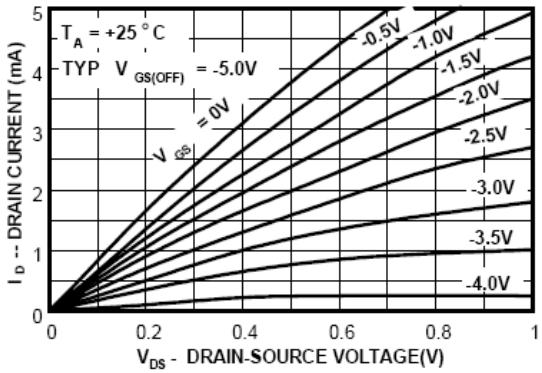


Figure 4. Common Drain-Source Characteristics

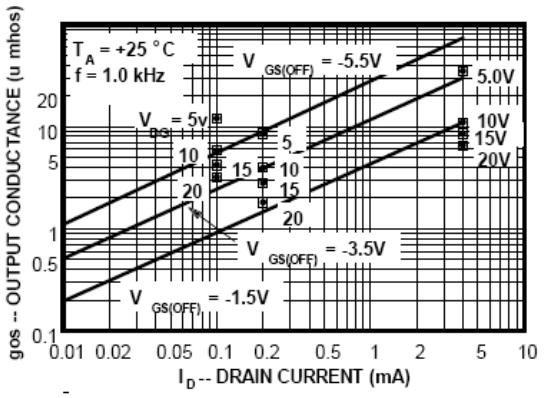


Figure 5. Output Conductance vs. Drain Current

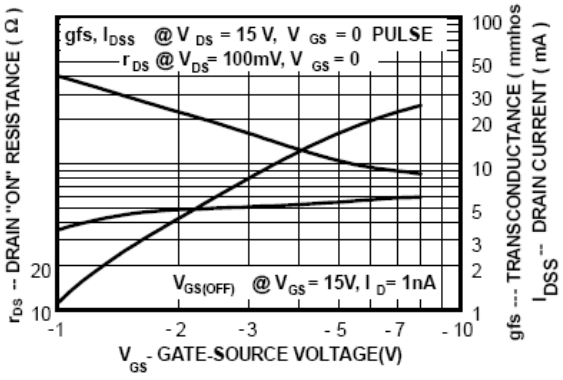


Figure 6. Transconductance Parameter Interactions

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TYPICAL CHARACTERISTICS (CONTINUED)

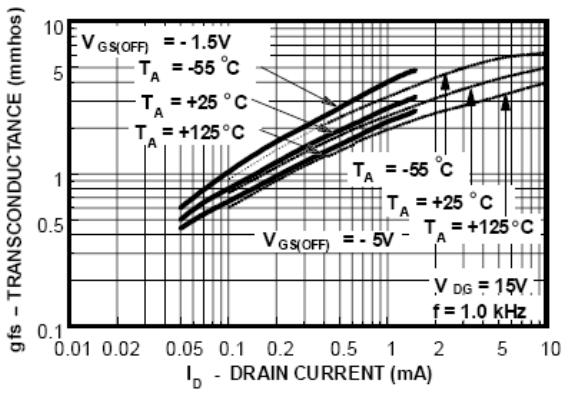


Figure 7. Transconductance vs. Drain Current

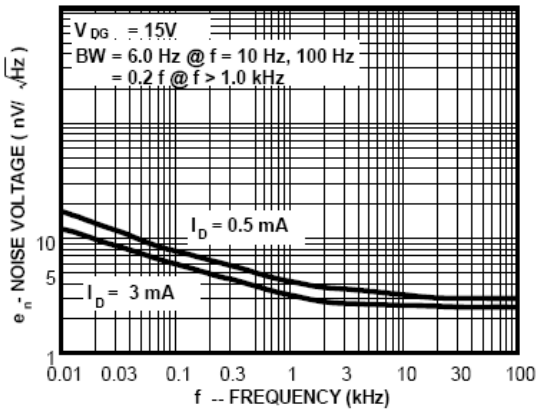


Figure 8. Noise Voltage vs. Frequency

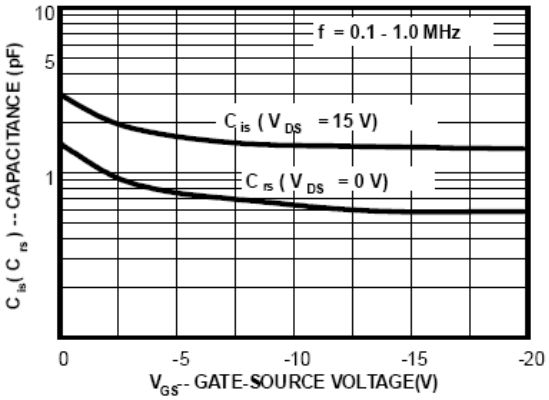


Figure 9. Capacitance vs. Voltage

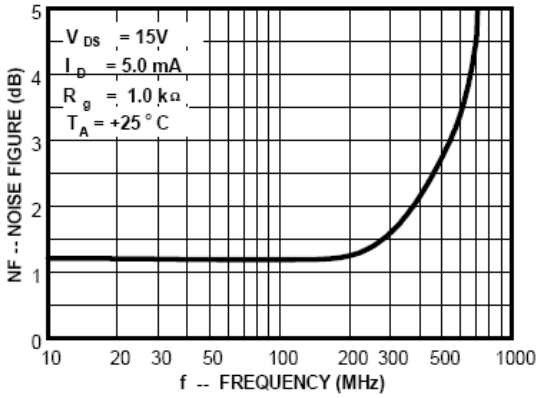


Figure 10. Noise Figure Frequency

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COMMON SOURCE CHARACTERISTICS

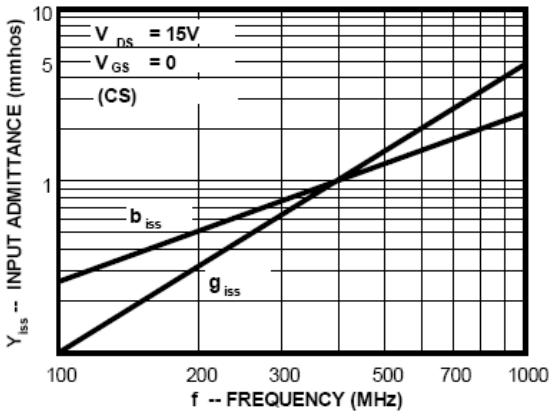


Figure 11. Input Admittance

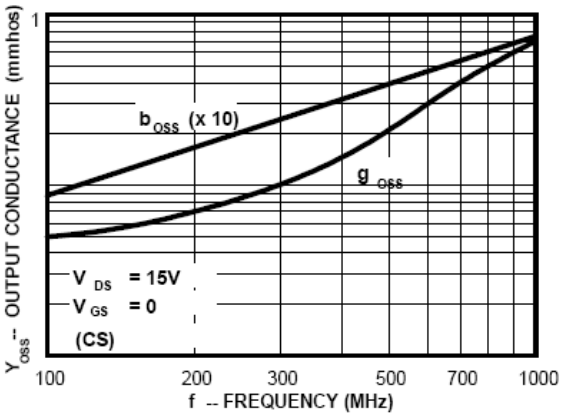


Figure 12. Output Admittance

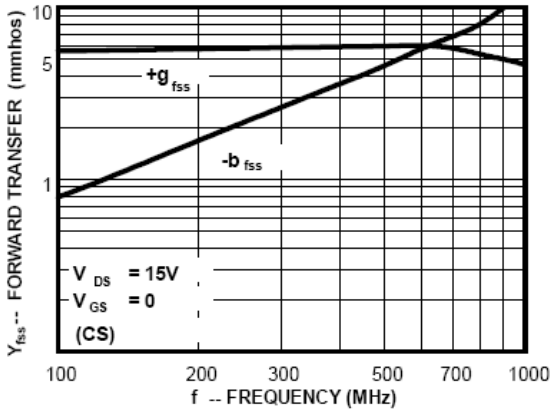


Figure 13. Forward Transadmittance

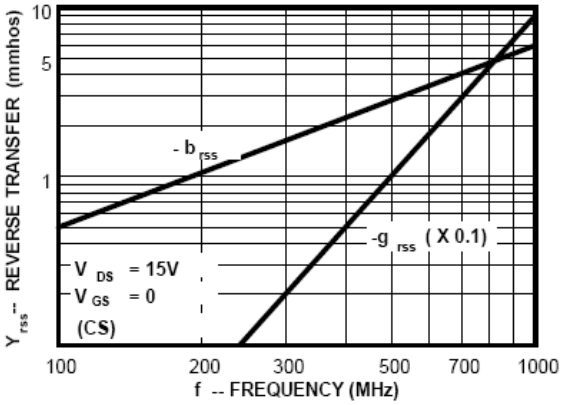


Figure 14. Reverse Transadmittance

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COMMON GATE CHARACTERISTICS

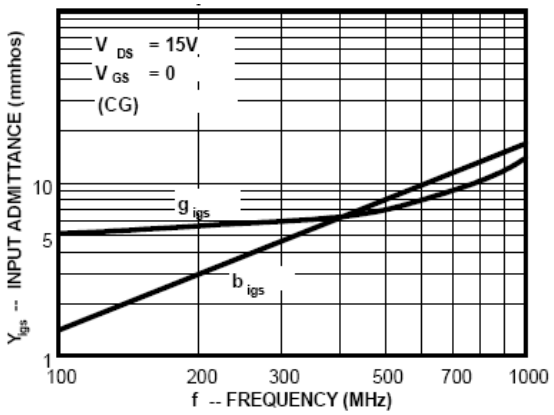


Figure 15. Input Admittance

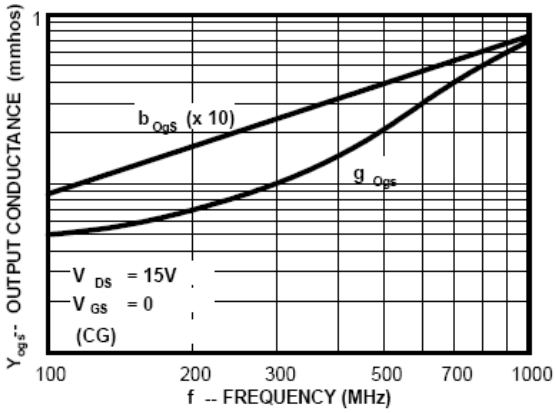


Figure 16. Output Admittance

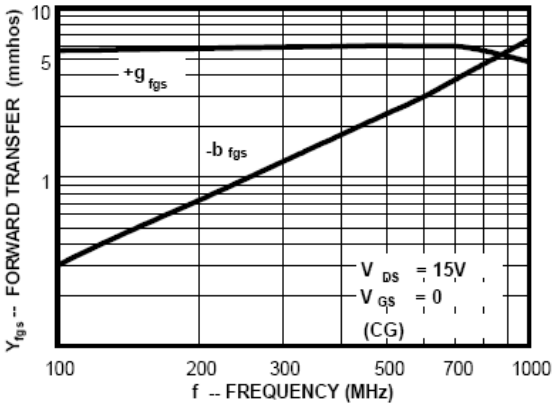


Figure 17. Forward Transadmittance

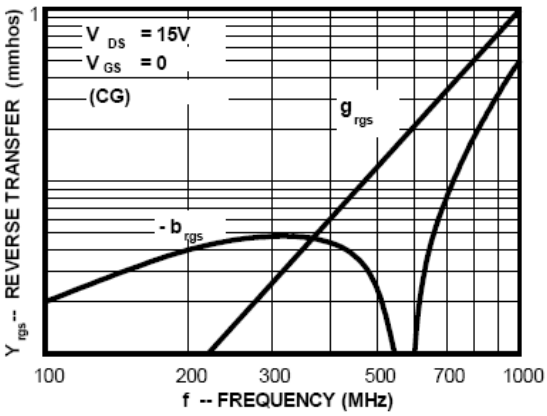


Figure 18. Reverse Transadmittance

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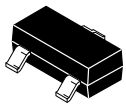
REVISION HISTORY

Revision	Description of Changes	Date
4	MMBF5486 OPN Marked as Discontinued.	01/19/2026

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

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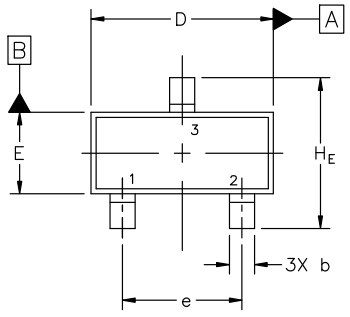
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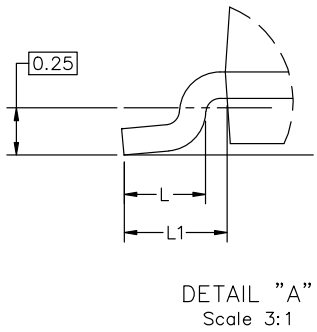
SCALE 4:1

SOT−23 (TO−236) 2.90x1.30x1.00 1.90P
CASE 318
ISSUE AU

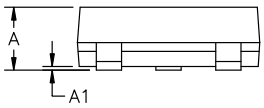
DATE 14 AUG 2024



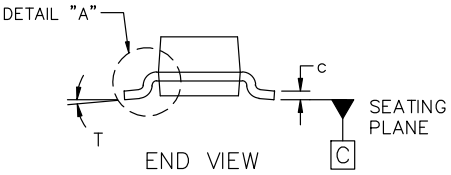
TOP VIEW



DETAIL "A"
Scale 3:1



SIDE VIEW

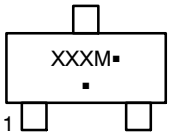


END VIEW

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.89	1.00	1.11
A1	0.01	0.06	0.10
b	0.37	0.44	0.50
c	0.08	0.14	0.20
D	2.80	2.90	3.04
E	1.20	1.30	1.40
e	1.78	1.90	2.04
L	0.30	0.43	0.55
L1	0.35	0.54	0.69
H_E	2.10	2.40	2.64
T	0°	−−−	10°

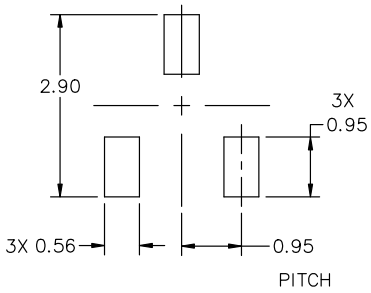
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED
MOUNTING FOOTPRINT

* For additional information on our Pb−Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DESCRIPTION:	**SOT−23 (TO−236) 2.90x1.30x1.00 1.90P**		**PAGE 1 OF 2**

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CASE 318
ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5:
CANCELLED

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 7:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 8:
PIN 1. ANODE
2. NO CONNECTION
3. CATHODE

STYLE 9:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 10:
PIN 1. DRAIN
2. SOURCE
3. GATE

STYLE 11:
PIN 1. ANODE
2. CATHODE
3. CATHODE−ANODE

STYLE 12:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 13:
PIN 1. SOURCE
2. DRAIN
3. GATE

STYLE 14:
PIN 1. CATHODE
2. GATE
3. ANODE

STYLE 15:
PIN 1. GATE
2. CATHODE
3. ANODE

STYLE 16:
PIN 1. ANODE
2. CATHODE
3. CATHODE

STYLE 17:
PIN 1. NO CONNECTION
2. ANODE
3. CATHODE

STYLE 18:
PIN 1. NO CONNECTION
2. CATHODE
3. ANODE

STYLE 19:
PIN 1. CATHODE
2. ANODE
3. CATHODE−ANODE

STYLE 20:
PIN 1. CATHODE
2. ANODE
3. GATE

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 22:
PIN 1. RETURN
2. OUTPUT
3. INPUT

STYLE 23:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 24:
PIN 1. GATE
2. DRAIN
3. SOURCE

STYLE 25:
PIN 1. ANODE
2. CATHODE
3. GATE

STYLE 26:
PIN 1. CATHODE
2. ANODE
3. NO CONNECTION

STYLE 27:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

STYLE 28:
PIN 1. ANODE
2. ANODE
3. ANODE

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